

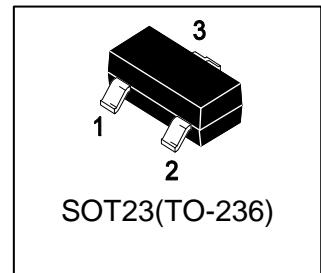
LBAS21SLT1G

S-LBAS21SLT1G

High Voltage Switching Diode

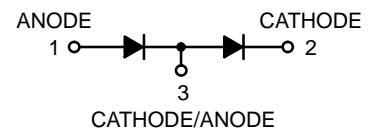
1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.



2. DEVICE MARKING AND RESISTOR VALUES

Device	Marking	Shipping
LBAS21SLT1G	JT	3000/Tape&Reel
LBAS21SLT3G	JT	10000/Tape&Reel



3. MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Continuous reverse voltage	VR	250	V
Peak Forward Current	IF	225	mA
Peak Forward Surge Current	IFM	625	mA

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation FR-5 Board, (Note 1) TA = 25°C Derate above 25°C	PD	225 1.8	mW mW/ $^\circ\text{C}$
Thermal resistance from junction to ambient	R _{θJA}	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 2) TA = 25°C Derate above 25°C	PD	300 2.4	mW mW/ $^\circ\text{C}$
Thermal resistance from junction to ambient	R _{θJA}	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T _J , T _{stg}	-55~+150	$^\circ\text{C}$

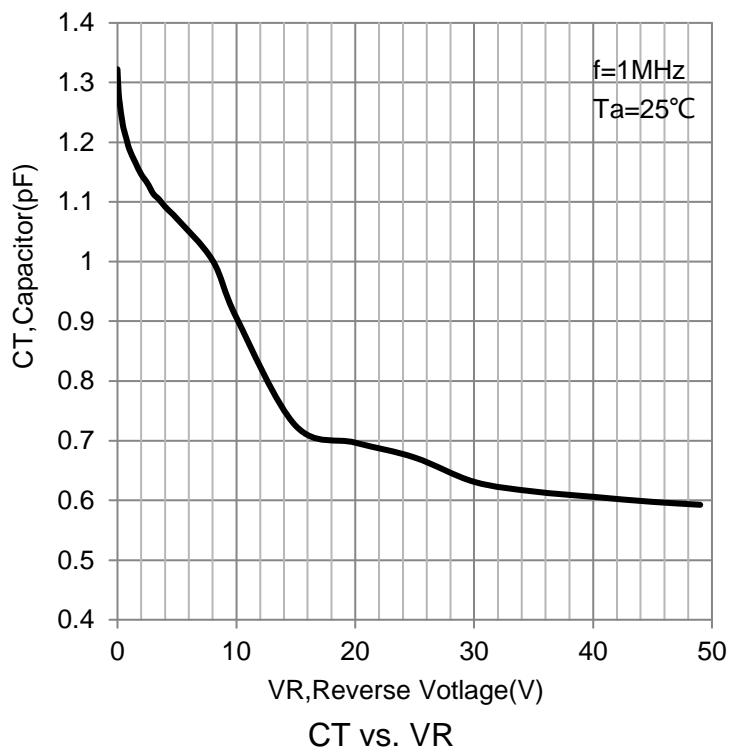
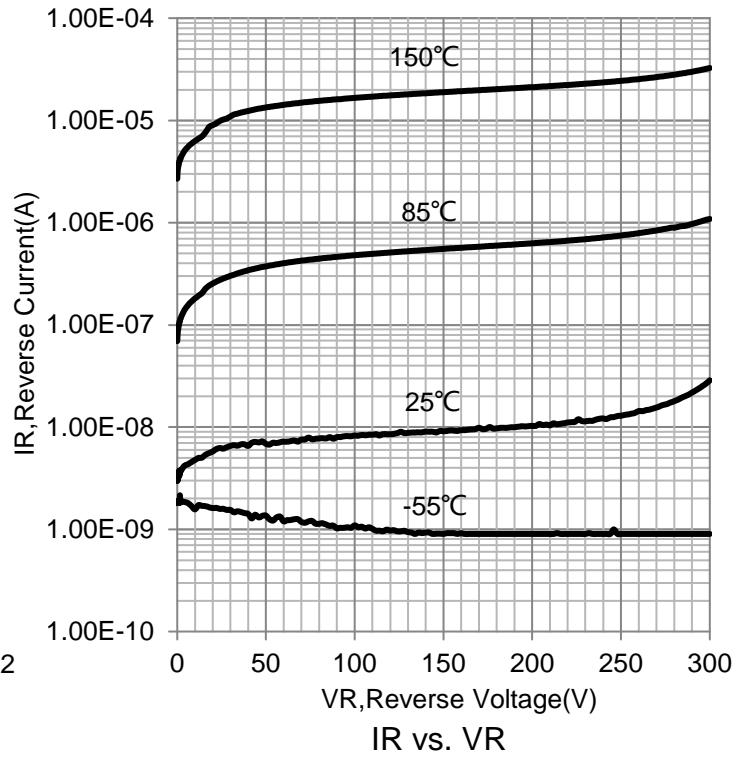
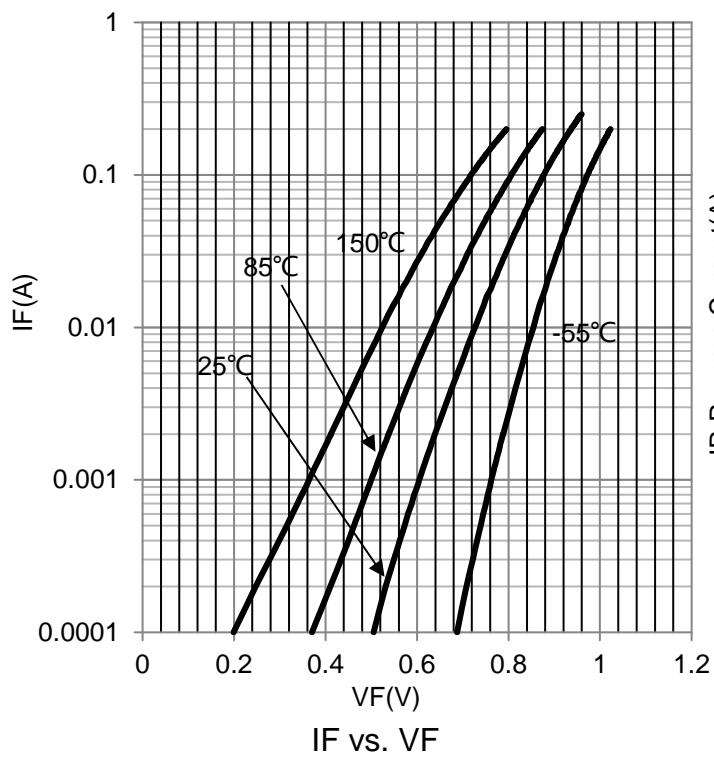
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

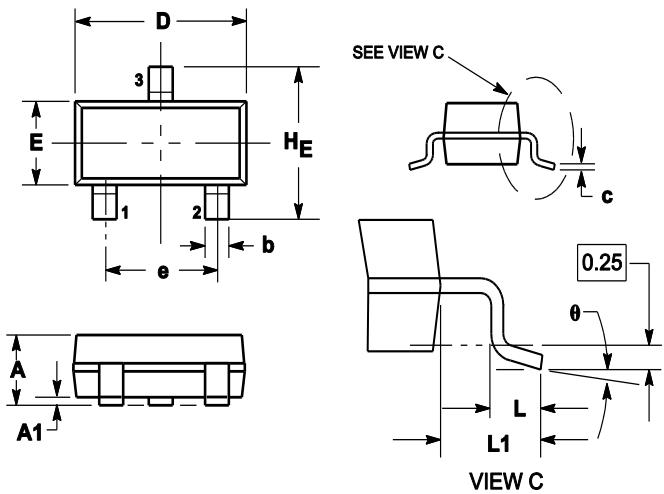
5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

CHARACTERISTICS	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current (VR=200V) (VR=200V, TJ = 150°C)	IR	- -	0.1 100	µA
Reverse Breakdown Voltage (IBR = 100 µA)	VBR	250	-	V
Forward voltage (IF =100mA) (IF =200mA)	VF	- -	1000 1250	mV
Diode capacitance (f=1MHz, VR =0)	Cd	-	5	pF
Reverse Recovery Time (IF = IR = 30mA, RL = 100Ω)	Trr	-	50	nS

6.ELECTRICAL CHARACTERISTICS CURVES



7. OUTLINE AND DIMENSIONS

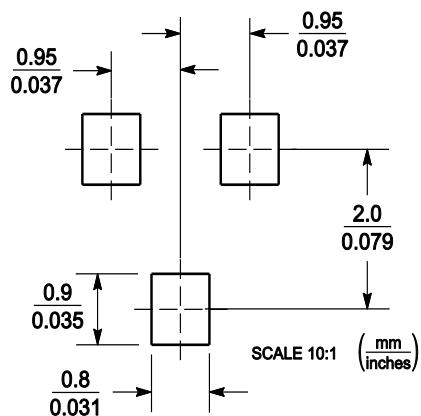


Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1	1.11	0.035	0.04	0.044
A1	0.01	0.06	0.1	0.001	0.002	0.004
b	0.37	0.44	0.5	0.015	0.018	0.02
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.9	3.04	0.11	0.114	0.12
E	1.20	1.3	1.4	0.047	0.051	0.055
e	1.78	1.9	2.04	0.07	0.075	0.081
L	0.10	0.2	0.3	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
H_E	2.10	2.4	2.64	0.083	0.094	0.104
θ	0°	---	10°	0°	---	10°

8. SOLDERING FOOTPRINT



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